

N-channel Silicon MOSFET

2SK2378

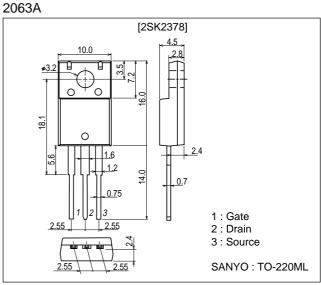
Ultrahigh-Speed Switching Applications

Features

- Low ON-resistance.
- · Ultrahigh-speed switching.
- Low-voltage drive.
- · Micaless package facilitaing mounting.

Package Dimensions

unit : mm



Specifications

Absolute Maximum Ratings at Ta= $25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		200	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	۱ _D		13	А
Drain Current (Pulse)	IDP	PW≤10µs, duty cycle≤1%	52	А
Allowable Power Dissipation	PD		2.0	W
	PD	Tc=25°C	30	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150 °C	

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions		Ratings		
	Symbol		min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0	200			V
Gate-to-Source Breakdown Voltage	V(BR)GSS	IG=±100μA, VDS=0	±20			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =200V, V _{GS} =0			100	μΑ
Gate-to-Source Leakage Current	IGSS	V _{GS} =±16V, V _{DS} =0			±10	μA
Cutoff Voltage	VGS(off)	VDS=10V, ID=1mA	1.5		2.5	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =7A	5	8.5		S

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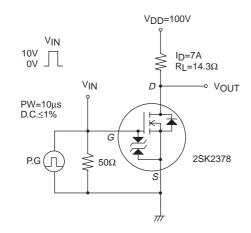
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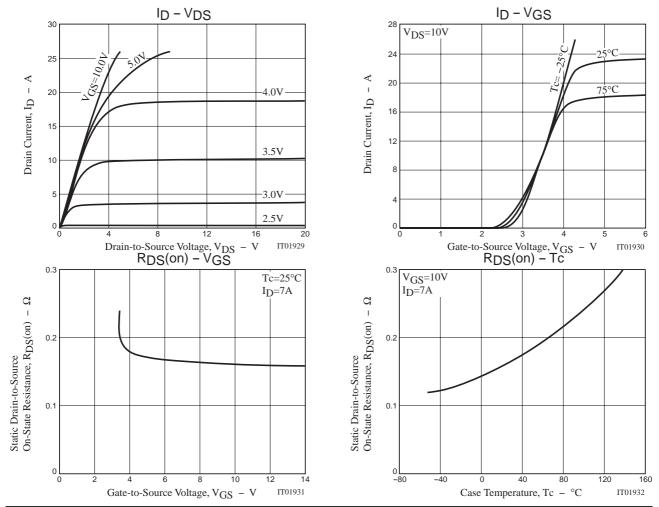
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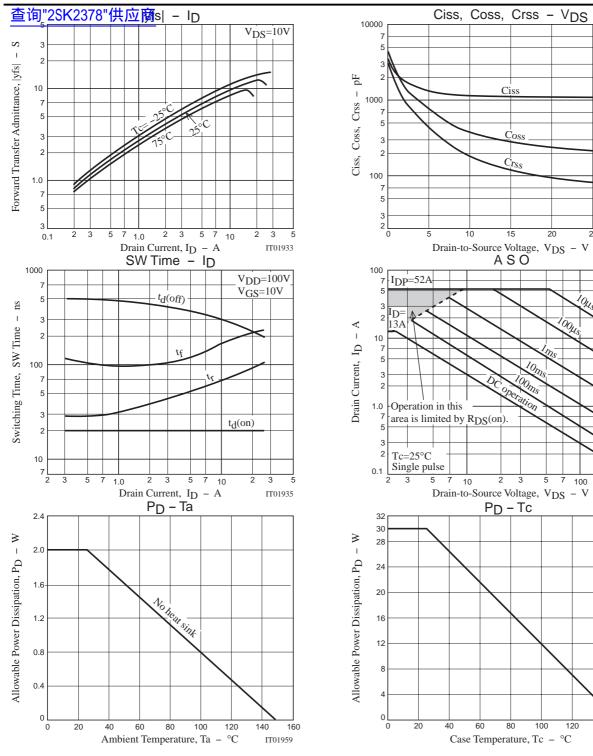
Parameter	Symbol	Conditions	Ratings			
			min	typ	max	Unit
Static Drain-to-Source On-State Resistance	R _{DS} (on)	I _D =7A, V _{GS} =10V		160	210	mΩ
Input Capacitance	Ciss	V _{DS} =20V, f=1MHz		1100		pF
Output Capacitance	Coss	V _{DS} =20V, f=1MHz		240		pF
Reverse Transfer Capacitance	Crss	V _{DS} =20V, f=1MHz		95		pF
Turn-ON Delay Time	t _d (on)	See specified Test Circuit		20		ns
Rise Time	tr	See specified Test Circuit		50		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit		340		ns
Fall Time	tf	See specified Test Circuit		140		ns
Diode Forward Voltage	VSD	IS=13A, VGS=0		1.0	1.5	V

Marking : K2378

Switching Time Test Circuit







f=1MHz

Coss

7 100

IT01958

100ms

IT01960

IT01934

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